NSN 5961-01-115-6666

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-115-6666 **Inclosure Material:** Glass **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.175 inches and 0.205 inches **End Application:** Pwrspyr2129/u Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 2.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: